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(54) **WIDE-BAND ACOUSTICALLY COUPLED THIN-FILM BAW FILTER**

(71) Applicant: **Teknologian tutkimuskeskus VTT Oy**, Espoo (FI)

(72) Inventors: **Johanna Meltaus**, Espoo (FI); **Tuomas Pensala**, Espoo (FI)

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(57) **ABSTRACT**

The invention relates to an acoustically coupled thin-film BAW filter, comprising a piezoelectric layer, an input-port on the piezoelectric layer changing electrical signal into an acoustic wave (SAW, BAW), and an output-port on the piezoelectric layer changing acoustic signal into electrical signal. In accordance with the invention the ports include electrodes positioned close to each other, and the filter is designed to operate in first order thickness-extensional TE1 mode.